



30V N-Channel Enhancement Mode MOSFET - ESD Protected

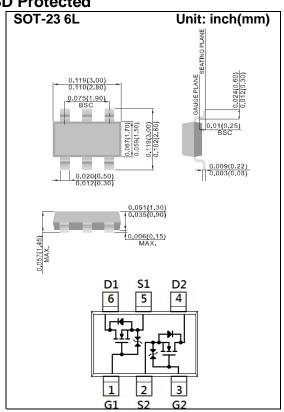
Voltage 30 V Current 1.6A

Features

- RDS(ON), VGS@4,5V, ID@1.6A<200mΩ
- RDS(ON), VGS@2.5V, ID@1.1A<270mΩ
- RDS(ON), VGS@1.8V, ID@0.2A<570mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.0141 grams
- Marking: SG2



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	30	V
Gate-Source Voltage		V_{GS}	<u>+</u> 8	V
Continuous Drain Current		I _D	1.6	Α
Pulsed Drain Current (Note 4)		I _{DM}	6.4	Α
Power Dissipation	T _a =25°C	P _D	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.5	0.78	1.3	V		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =1.6A	-	145	200	mΩ		
		V _{GS} =2.5V, I _D =1.1A	-	185	270			
		V_{GS} =1.8V, I_{D} =0.2A	1	330	570			
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =30V, V_{GS} =0V	-	0.01	1	uA		
Gate-Source Leakage Current	I _{GSS}	$V_{GS}=\underline{+}8V, V_{DS}=0V$	-	1.4	<u>+</u> 10	uA		
Dynamic ^(Note 5)								
Total Gate Charge	Q_g	V _{DS} =15V, I _D =1.6A, V _{GS} =4.5V ^(Note 1,2)	-	1.5	-	nC		
Gate-Source Charge	Q_gs		-	0.3	-			
Gate-Drain Charge	Q_gd		-	0.3	-			
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V, f=1.0MHZ	-	93	-	pF		
Output Capacitance	Coss		-	19	-			
Reverse Transfer Capacitance	Crss	I=1.0IVII IZ	-	6	-			
Turn-On Delay Time	td _(on)	\/ 15\/ 1.6A	-	6.4	-			
Turn-On Rise Time	tr	V_{DD} =15V, I_{D} =1.6A, V_{GS} =4.5V, R_{G} =6 Ω (Note 1.2)	-	33	-	ns		
Turn-Off Delay Time	td _(off)		-	37	-			
Turn-Off Fall Time	tf	11G-012	-	32	-			
Drain-Source Diode								
Maximum Continuous Drain-Source					1.0	А		
Diode Forward Current	I _S		_	_	1.0			
Diode Forward Voltage	V_{SD}	I _S =1.0A, V _{GS} =0V	-	0.81	1.2	V		

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

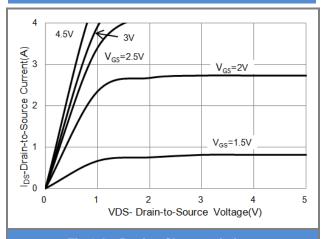


Fig.1 On-Region Characteristics

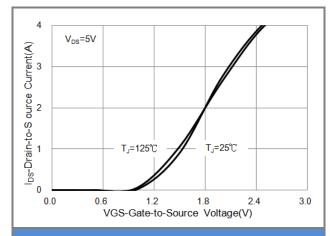


Fig.2 Transfer Characteristics

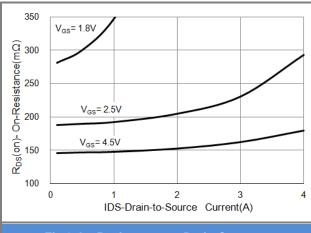


Fig.3 On-Resistance vs. Drain Current

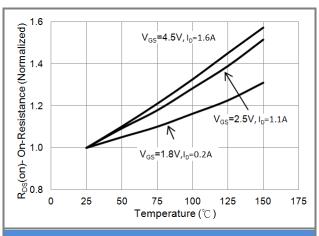


Fig.4 On-Resistance vs. Junction temperature

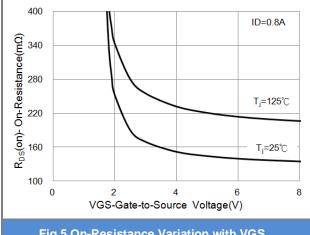


Fig.5 On-Resistance Variation with VGS.

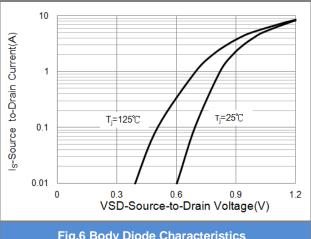


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

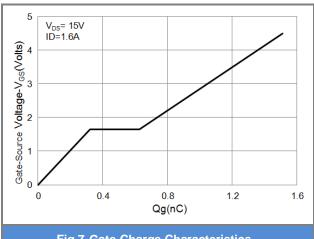


Fig.7 Gate-Charge Characteristics

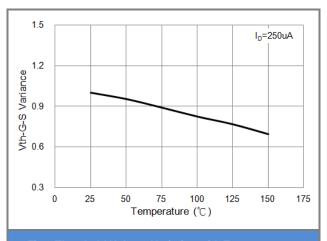


Fig.8 Threshold Voltage Variation with Temperature.

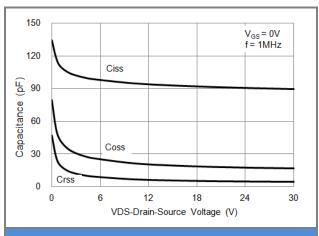


Fig.9 Capacitance vs. Drain-Source Voltage.

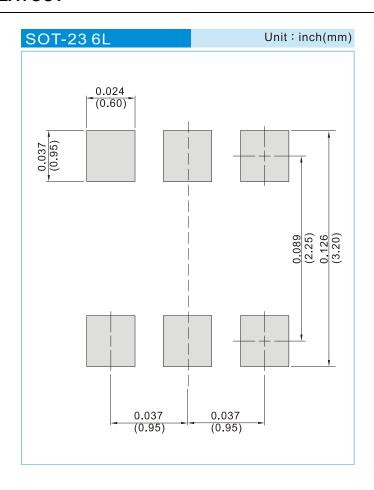




PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing type	Marking	Version
PJS6832_S1_00001	SOT-23 6L	3K pcs / 7" reel	SG2	Halogen free
PJS6832_S2_00001	SOT-23 6L	10K pcs / 13" reel	SG2	Halogen free

MOUNTING PAD LAYOUT







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